



**TIP110/112
TIP115/117**

COMPLEMENTARY SILICON POWER DARLINGTON TRANSISTORS

- STMicroelectronics PREFERRED SALES TYPES
- COMPLEMENTARY PNP - NPN DEVICES
- MONOLITHIC DARLINGTON CONFIGURATION
- INTEGRATED ANTIPARALLEL COLLECTOR-EMITTER DIODE

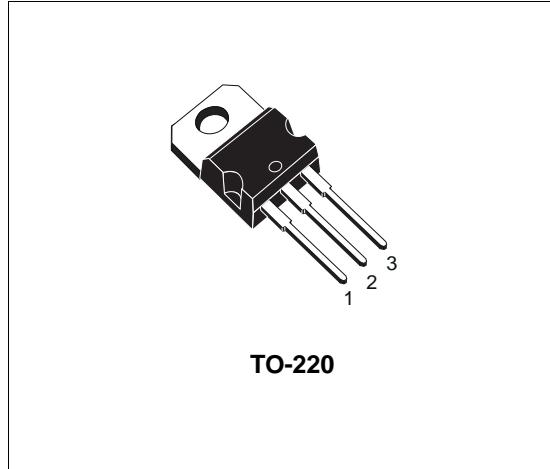
APPLICATIONS

- LINEAR AND SWITCHING INDUSTRIAL EQUIPMENT

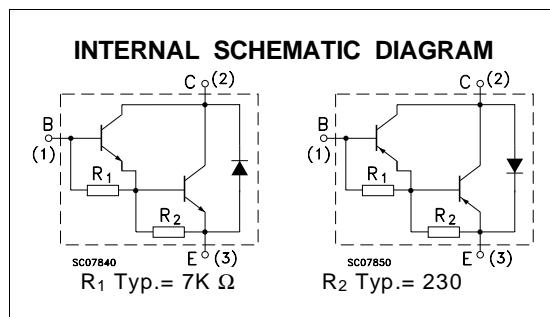
DESCRIPTION

The TIP110 and TIP112 are silicon Epitaxial-Base NPN transistors in monolithic Darlington configuration mounted in Jedec TO-220 plastic package. They are intended for use in medium power linear and switching applications.

The complementary PNP types are TIP115 and TIP117.



TO-220



ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | | | | Unit |
|-----------|--|-------|--------|------------|-----|------------------|
| | | NPN | TIP110 | TIP112 | PNP | |
| | | | TIP115 | TIP117 | | |
| V_{CBO} | Collector-Base Voltage ($I_E = 0$) | | 60 | 100 | | V |
| V_{CEO} | Collector-Emitter Voltage ($I_B = 0$) | | 60 | 100 | | V |
| V_{EBO} | Emitter-Base Voltage ($I_C = 0$) | | | 5 | | V |
| I_C | Collector Current | | | 2 | | A |
| I_{CM} | Collector Peak Current | | | 4 | | A |
| I_B | Base Current | | | 50 | | mA |
| P_{tot} | Total Dissipation at $T_{case} \leq 25^\circ\text{C}$ $T_{amb} \leq 25^\circ\text{C}$ | | | 50 | | W |
| T_{stg} | Storage Temperature | | | -65 to 150 | | $^\circ\text{C}$ |
| T_j | Max. Operating Junction Temperature | | | 150 | | $^\circ\text{C}$ |

* For PNP types voltage and current values are negative

TIP110/TIP112/TIP115/TIP117

THERMAL DATA

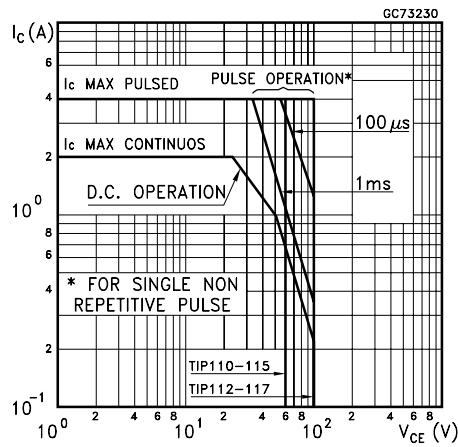
| | | | | |
|----------------|-------------------------------------|-----|------|-----------------------------|
| $R_{thj-case}$ | Thermal Resistance Junction-case | Max | 2.5 | $^{\circ}\text{C}/\text{W}$ |
| $R_{thj-amb}$ | Thermal Resistance Junction-ambient | Max | 62.5 | $^{\circ}\text{C}/\text{W}$ |

ELECTRICAL CHARACTERISTICS ($T_{case} = 25 \text{ }^{\circ}\text{C}$ unless otherwise specified)

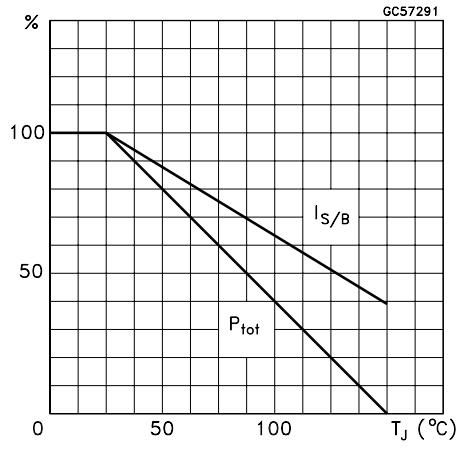
| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|-----------------|--|--|-------------|------|------|--------|
| I_{CEO} | Collector Cut-off Current ($I_B = 0$) | $V_{CE} = \text{Half Rated } V_{CEO}$ | | | 2 | mA |
| I_{CBO} | Collector Cut-off Current ($I_E = 0$) | $V_{CB} = \text{Rated } V_{CBO}$ | | | 1 | mA |
| I_{EBO} | Emitter Cut-off Current ($I_C = 0$) | $V_{EB} = 5 \text{ V}$ | | | 2 | mA |
| $V_{CEO(sus)*}$ | Collector-Emitter Sustaining Voltage ($I_B = 0$) | $I_C = 30 \text{ mA}$ for TIP110/115 for TIP112/117 | 60 100 | | | V V |
| $V_{CE(sat)*}$ | Collector-Emitter Saturation Voltage | $I_C = 2 \text{ A}$ $I_B = 8 \text{ mA}$ | | | 2.5 | V |
| V_{BE*} | Base-Emitter Voltage | $I_C = 2 \text{ A}$ $V_{CE} = 4 \text{ V}$ | | | 2.8 | V |
| h_{FE*} | DC Current Gain | $I_C = 1 \text{ A}$ $V_{CE} = 4 \text{ V}$ $I_C = 2 \text{ A}$ $V_{CE} = 4 \text{ V}$ | 1000 500 | | | |

* Pulsed: Pulse duration = 300 μs , duty cycle 1.5 %
For PNP types voltage and current values are negative.

Safe Operating Areas

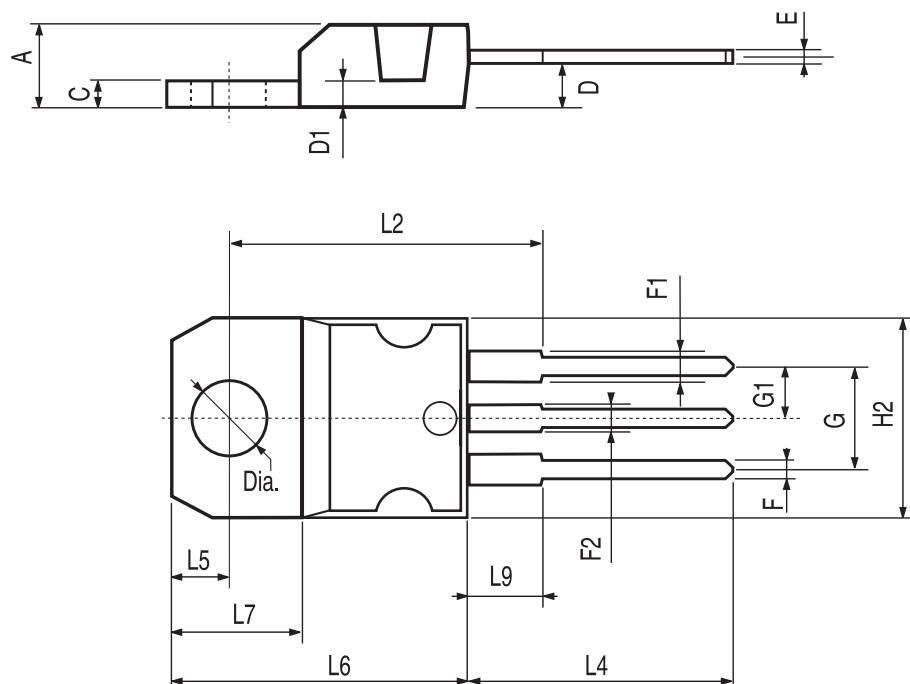


Derating Curve



TO-220 MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|-------|------|-------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 4.40 | | 4.60 | 0.173 | | 0.181 |
| C | 1.23 | | 1.32 | 0.048 | | 0.051 |
| D | 2.40 | | 2.72 | 0.094 | | 0.107 |
| D1 | | 1.27 | | | 0.050 | |
| E | 0.49 | | 0.70 | 0.019 | | 0.027 |
| F | 0.61 | | 0.88 | 0.024 | | 0.034 |
| F1 | 1.14 | | 1.70 | 0.044 | | 0.067 |
| F2 | 1.14 | | 1.70 | 0.044 | | 0.067 |
| G | 4.95 | | 5.15 | 0.194 | | 0.203 |
| G1 | 2.4 | | 2.7 | 0.094 | | 0.106 |
| H2 | 10.0 | | 10.40 | 0.393 | | 0.409 |
| L2 | | 16.4 | | | 0.645 | |
| L4 | 13.0 | | 14.0 | 0.511 | | 0.551 |
| L5 | 2.65 | | 2.95 | 0.104 | | 0.116 |
| L6 | 15.25 | | 15.75 | 0.600 | | 0.620 |
| L7 | 6.2 | | 6.6 | 0.244 | | 0.260 |
| L9 | 3.5 | | 3.93 | 0.137 | | 0.154 |
| DIA. | 3.75 | | 3.85 | 0.147 | | 0.151 |



P011C